

Intra-granular Ti precipitates in MgB_2

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Abstract

Superconducting magnesium diboride has been prepared with intra-granular TiB precipitates that have appropriate size and spacing for the pinning of superconducting vortices. The TiB particles have a size ranging from 1 nm to 20 nm and a spacing about 5 times as large. By co-depositing Ti and B on a commercial carbon coated silicon carbide substrate with chemical vapor deposition methods, it was possible to obtain a starting fiber with Ti well dispersed in the B . Reacting these fibers in a Mg vapor then transformed the fiber into a superconductor capable of carrying 10,000 A/cm^2 at 25 K and 1 T . The $Ti-B$ bonds are strong enough that there is relatively little migration of the Ti as the MgB_2 grains form around the TiB precipitates. TiB_2 precipitates, if they are present, can not be seen in the selected area diffraction pictures that show the TiB precipitates.

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In an important series of papers, Zhao and co-workers[1] showed that the critical current density, J_c , of MgB_2 could be substantially enhanced by Ti doping. Using a solid state reaction of ground powders of Mg , Ti , and B , they produced sintered pellets with $J_c \sim 5 \times 10^4$ A/cm² at 5 K and in 5 T. These were extremely small grained materials with MgB_2 grains approximately 10 nm in size having TiB_2 decorating the grain boundaries. High resolution transmission electron microscopy seemed to indicate that the TiB_2 was only one unit cell thick on the surface of the MgB_2 grains. No Ti was found within the MgB_2 grains. It was suggested that the presence of the TiB_2 limits the grain size of the MgB_2 . For optimum J_c , approximately 10% Ti replacing Mg is needed.

Samples of Ti -doped MgB_2 also can be prepared by a rather different chemical vapor deposition (CVD) approach.[2] In this CVD deposition, $TiCl_4$ is added to the BCl_3 and H_2 gas stream and the Ti -doped B is deposited on the conducting substrate at about 1100°C.[3] These Ti -doped fibers are subsequently placed in a Ta tube along with excess Mg and the fibers are transformed to MgB_2 in the Mg vapor.[4] These conductors typically show MgB_2 grains in range of 0.5 μm to 5 μm and critical current densities of 10,000 A/cm² at 25 K and 1.4 T.[5]. These enhancements are similar to those observed for SiC nano-particles in MgB_2 . [6]

The purpose of this work is to report a transmission electron microscope (TEM) study of the titanium boride precipitates in the MgB_2 matrix. Scanning electron microscope (SEM) pictures[3] show that the precipitates are small compared to the 1 μm SEM beam size, and they show no evidence of TiB_2 precipitates on grain boundaries as found for samples made by solid state diffusion from ground powders of the elements.[1] The goal here is to determine the size and distribution of the titanium boride precipitates and to look for intra-granular precipitates if they occur.

Titanium doped boron fibers are prepared in a reel-to-reel continuous flow CVD apparatus in which both the B and Ti are deposited onto a 75 μm diameter SiC fiber that has been coated with a few micrometers of glassy carbon (commercially available as $SCS - 9A$). The reactor is similar to those used to make commercial boron fiber. The reactant gas was predominantly BCl_3 and H_2 gas at atmospheric pressure. The H_2 gas is bubbled through liquid $TiCl_4$ at zero degrees centigrade to give a $TiCl_4$ partial pressure of about 2×10^{-3} bar. The substrate is drawn through the reactor at about 100 mm/s. The filament in the reactor was resistively heated to a peak temperature of about 1100°C. The resulting Ti -doped B

layer was about $10\text{ }\mu\text{m}$ thick. To form MgB_2 , short lengths of fiber are placed in a Ta tube with about three times excess Mg and sealed under Ar . This tube in turn was sealed in quartz and placed in a furnace at $950^\circ C$ for 2 h.[4] Scanning electron microscope chemical analysis with energy dispersive spectroscopy indicated variations in the Ti/Mg ratio of about three to five percent when a beam size of a $1\text{ }\mu\text{m}$ diameter scans the sample.

To form a transmission electron microscope (TEM) sample, pieces of the Ti -doped MgB_2 layer were flaked off the SiC substrate and crushed. The resulting powder was floated onto a holey carbon grid and grains having a thickness in the range of 100 to 200 nm were selected for study using a Philips $CM30\text{ }TEM$ operating at 300 keV .

A typical grain of Ti -doped MgB_2 is shown in Fig. 1. From the conditions of diffraction contrast in the TEM , the thickness of the MgB_2 grain is estimated to be about 100 to 200 nm . Typical precipitate size is 1 to 10 nm . Because the micrograph shows all the precipitates through the entire thickness, the spacing of the overlapping precipitates is substantially larger than the apparent separation of this image due to the through thickness projection and is estimated to be in the 20 to 50 nm range. If an energy dispersive spectrum (EDS) is taken over a large volume relative to the precipitate size, the Ti/Mg ratio is about 0.05 in accord with the values found with the SEM/EDS .

Tilting the grain so that a selected area diffraction pattern is taken with the beam covering an approximately 500 nm portion of the grain, a single hexagonal pattern is seen that indexes to be MgB_2 as shown by Fig. 2. The ring patterns are presumably caused by the precipitates and would indicate that the precipitates are randomly oriented. The crystal structure of TiB_2 is very close to MgB_2 with nearly the same lattice constant. Hence the smaller rings probably do not arise from TiB_2 .

If the beam is tilted off the c -axis a few degrees, the ring structure is more easily seen as shown by Fig. 3. The three most prominent rings index well for the (111), the (200), and the (220) lines of TiB . If there is TiB_2 present, it is too small in volume to be observed here. This is to be contrasted with the work of Zhao and coworkers.[1] They found that samples prepared by solid state reaction of powders of Ti , Mg , and B gave TiB_2 precipitates on the grain boundaries of the MgB_2 grains and no intra-granular precipitates. It was a surprise to find the dominant intra-granular precipitate to be TiB . These results indicate that the introduction of Ti impurities into the B before the Mg is introduced, leads to a final morphology and type of the Ti precipitates different from the precipitates found from

solid state reaction of ground powders.[1]

Critical current performance of these materials produced by *CVD* are illustrated in Fig. 4. At 5 *K*, J_c derived from magnetization measurements[4] drop from about 4×10^6 *A/cm*² in self field to about 50,000 *A/cm*² at 5 *T*. At 25 *K*, J_c drops from about 900,000 *A/cm*² in self field to about 1,000 *A/cm*² at 1.5 *T*. For this material, the Meissner screening in 50 *Oe* drops from zero at 36 *K* to 70 *G* at 32 *K*, so the effective T_c has been suppressed by about 5 *K*.

In summary, *Ti*-doped MgB_2 can prepared with a fairly uniform array of intra-granular precipitates that is well suited for flux pinning and high critical current densities. The *Ti* and *B* can be co-deposited by *CVD* methods that are similar to those used to make commercial boron fiber. Then, the material can be converted to MgB_2 in *Mg* vapor. The resulting *Ti*-doped MgB_2 is found to have a dense array of randomly oriented *TiB* precipitates have dimensions of about 1 to 10 *nm* and a separation 10 to 50 *nm*. Critical current densities are substantially enhanced over the pure MgB_2 material.

Acknowledgments

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FIG. 1: *TEM* micrograph of a single grain of MgB_2 that is about 100 to 200 *nm* thick.

FIG. 2: *TEM* diffraction pattern for a large area of the grain indicating a hexagonal pattern that indexes to MgB_2 . The ring patterns presumably arise from the precipitates.

FIG. 4: Critical current density for *Ti*-doped MgB_2 .

FIG. 3: Off axis *TEM* diffraction pattern makes the ring pattern easier to see. The three most prominent rings index for TiB .

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